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Team Nexperia

Quad 2-input OR gate Rev. 6 — 3 December 2015

### 1. General description

The 74HC32; 74HCT32 is a quad 2-input OR gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

### 2. Features and benefits

- Complies with JEDEC standard JESD7A
- Input levels:
  - ◆ For 74HC32: CMOS level
  - ◆ For 74HCT32: TTL level
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C

## 3. Ordering information

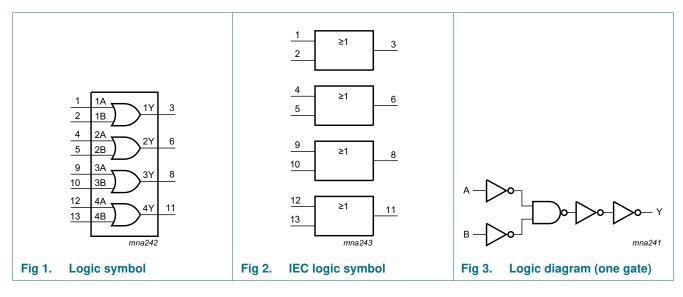
Table 1.	Ordering	information
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Type number	Package				
	Temperature range	Name	Description	Version	
74HC32D	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width	SOT108-1	
74HCT32D			3.9 mm		
74HC32DB	–40 °C to +125 °C	SSOP14	SOP14 plastic shrink small outline package; 14 leads; body \$		
74HCT32DB	1		width 5.3 mm		
74HC32PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1	
74HCT32PW			body width 4.4 mm		
74HC32BQ	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very	SOT762-1	
74HCT32BQ			thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm		



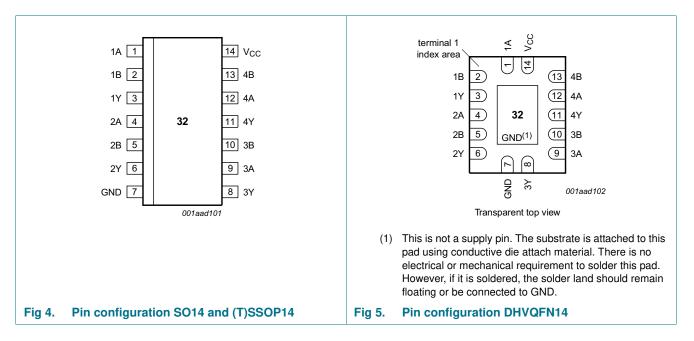
**Quad 2-input OR gate** 

### 4. Functional diagram



# 5. Pinning information

#### 5.1 Pinning



### 5.2 Pin description

Table 2.   Pin description		
Symbol	Pin	Description
1A to 4A	1, 4, 9, 12	data input
1B to 4B	2, 5, 10,13	data input
1Y to 4Y	3, 6, 8, 11	data output
GND	7	ground (0 V)
V <sub>CC</sub>	14	supply voltage

# 6. Functional description

#### Table 3. Function table<sup>[1]</sup>

Input		Output
nA	nB	nY
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

# 7. Limiting values

#### Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
l <sub>ок</sub>	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{O} < \text{V}_{CC} + 0.5 \text{ V}$		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	SO14, (T)SSOP14 and DHVQFN14 packages	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SO14 package: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.
 For (T)SSOP14 packages: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.
 For DHVQFN14 packages: P<sub>tot</sub> derates linearly with 4.5 mW/K above 60 °C.

# 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions 74HC32		74HCT32			Unit		
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

# 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	• +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	-
74HC32	I.		1	1			1	1		1
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current		-	-	±0.1	-	±1	-	±1	μA
I <sub>CC</sub>	supply current		-	-	2.0	-	20	-	40	μA

Quad 2-input OR gate

#### Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT3	2						1	1		1
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 V \text{ to } 5.5 V$	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 5.2 mA	-	0.15	0.25	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1	-	±1	μA
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} \text{ or } GND; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	2.0	-	20	-	40	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A};$ other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	430	-	540	-	590	μA
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

**Quad 2-input OR gate** 

# **10. Dynamic characteristics**

#### Table 7. Dynamic characteristics

 $GND = 0 V; C_L = 50 pF;$  for test circuit see <u>Figure 7</u>.

Symbol	Parameter	Conditions			25 °C		–40 °C to	Unit	
				Min	Тур	Max	Max (85 °C)	Max (125 °C)	_
74HC32			1			1		-	
t <sub>pd</sub>	propagation delay	nA, nB to nY; see Figure 6	[1]						
		V <sub>CC</sub> = 2.0 V		-	22	90	115	135	ns
		V <sub>CC</sub> = 4.5 V		-	8	18	23	27	ns
		$V_{CC} = 5.0 \text{ V}; C_{L} = 15 \text{ pF}$		-	6	-	-	-	ns
		V <sub>CC</sub> = 6.0 V		-	6	15	20	23	ns
tt	transition time	see <u>Figure 6</u>	[2]						
		V <sub>CC</sub> = 2.0 V		-	19	75	95	110	ns
		V <sub>CC</sub> = 4.5 V		-	7	15	19	22	ns
		V <sub>CC</sub> = 6.0 V		-	6	13	16	19	ns
C <sub>PD</sub>	power dissipation capacitance	per package; $V_1 = GND$ to $V_{CC}$	[3]	-	16	-	-	-	pF
74HCT3	2	l			1	-	+	1	1
t <sub>pd</sub>	propagation delay	nA, nB to nY; see Figure 6	<u>[1]</u>						
		V <sub>CC</sub> = 4.5 V		-	11	24	30	36	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	9	-	-	-	ns
tt	transition time	$V_{CC} = 4.5 \text{ V}; \text{ see } \frac{\text{Figure 6}}{1000}$	[2]	-	7	15	19	22	ns
C <sub>PD</sub>	power dissipation capacitance	per package; V <sub>I</sub> = GND to V <sub>CC</sub> – 1.5 V	<u>[3]</u>	-	28	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

 $P_{D}$  =  $C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N$  +  $\sum$   $(C_{L} \times V_{CC}{}^{2} \times f_{o})$  where:

 $f_i = input frequency in MHz;$ 

 $f_o = output frequency in MHz;$ 

 $C_L$  = output load capacitance in pF;

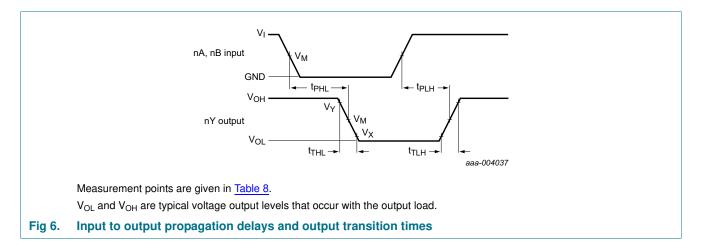
 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\sum$  (C\_L  $\times$   $V_{CC}{}^2 \times f_o)$  = sum of outputs.

Quad 2-input OR gate

# 11. Waveforms



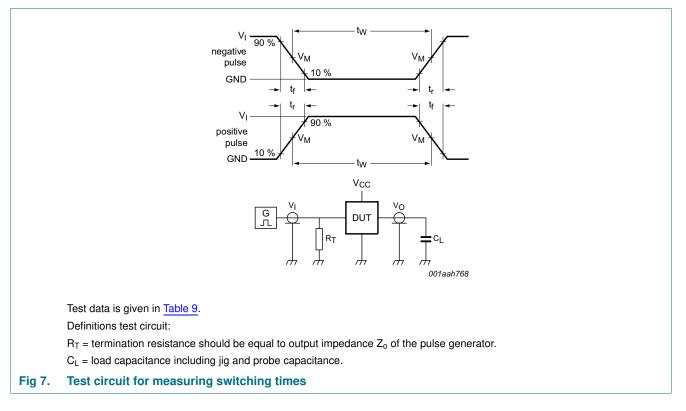
#### Table 8. Measurement points

Туре	Input	Output			
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>	
74HC32	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	0.1V <sub>CC</sub>	0.9V <sub>CC</sub>	
74HCT32	1.3 V	1.3 V	0.1V <sub>CC</sub>	0.9V <sub>CC</sub>	

### **NXP Semiconductors**

# 74HC32; 74HCT32

#### Quad 2-input OR gate

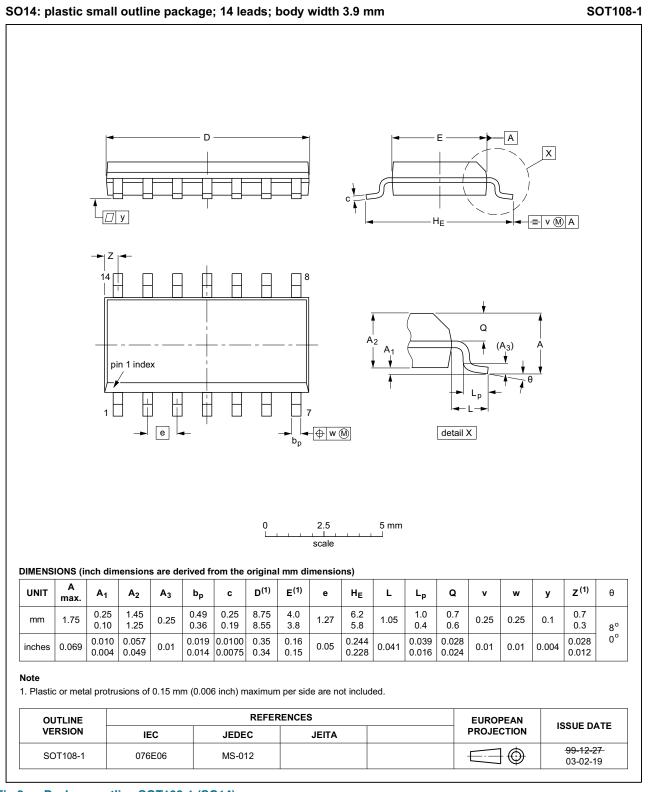


#### Table 9. Test data

Туре	Input Lo		Load	Test
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	
74HC32	V <sub>CC</sub>	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>
74HCT32	3.0 V	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

**Quad 2-input OR gate** 

### 12. Package outline

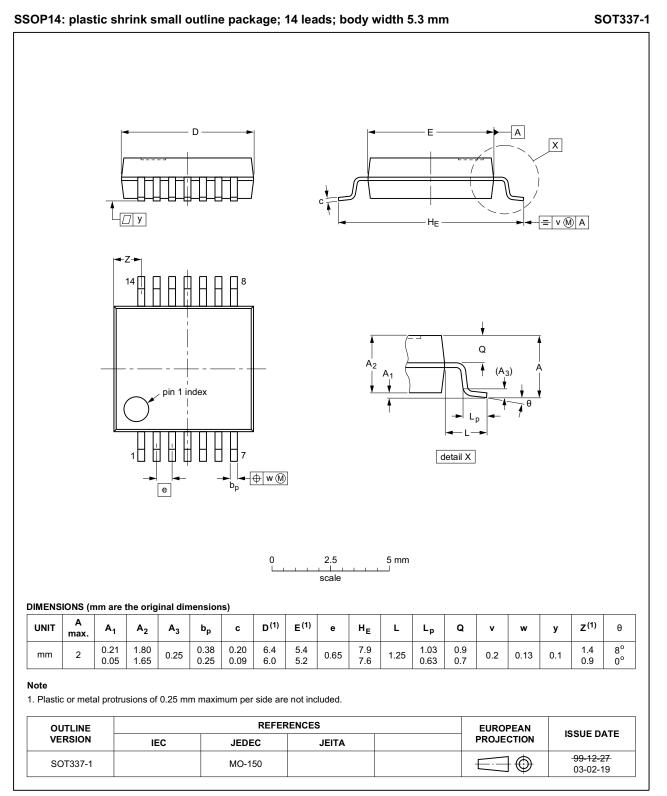


#### Fig 8. Package outline SOT108-1 (SO14)

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Quad 2-input OR gate



#### Fig 9. Package outline SOT337-1 (SSOP14)

74HC\_HCT32

**Quad 2-input OR gate** 

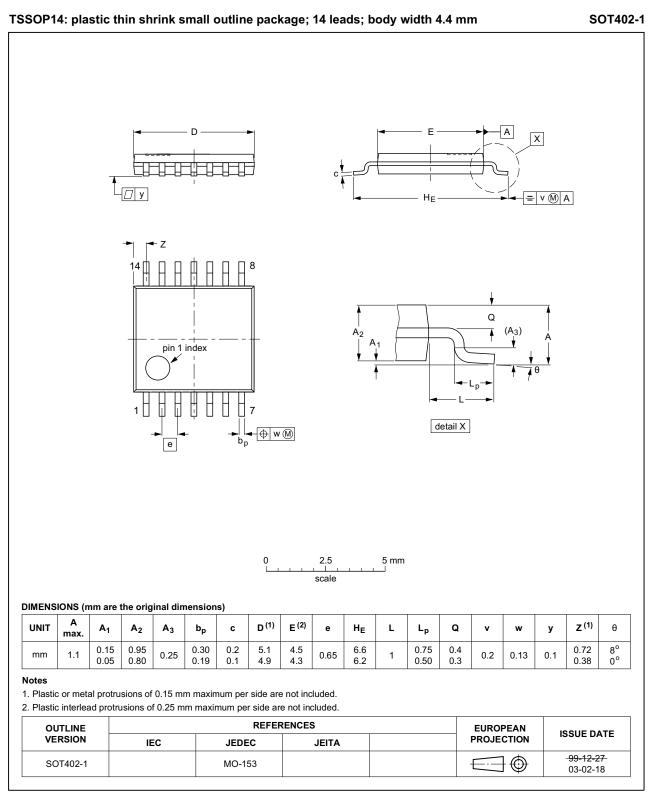
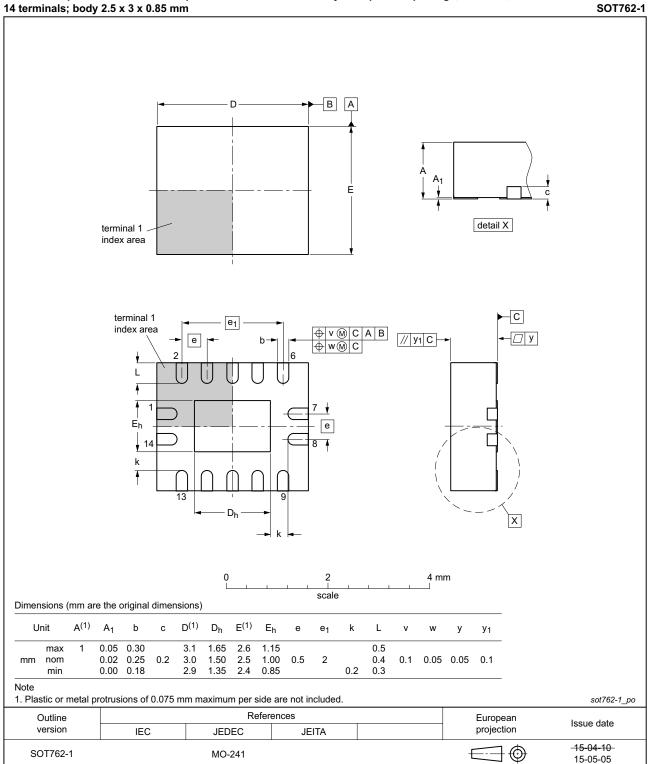


Fig 10. Package outline SOT402-1 (TSSOP14)

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**Quad 2-input OR gate** 



DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads;

#### Fig 11. Package outline SOT762-1 (DHVQFN14)

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74HC\_HCT32

# **13. Abbreviations**

Table 10. Abb	Table 10. Abbreviations					
Acronym	Description					
CMOS	Complementary Metal-Oxide Semiconductor					
DUT	Device Under Test					
ESD	ElectroStatic Discharge					
НВМ	Human Body Model					
MM	Machine Model					
TTL	Transistor-Transistor Logic					

# 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT32 v.6	20151203	Product data sheet	-	74HC_HCT32 v.5
Modifications:	Type numbers 74HC32N and 74HCT32N (SOT27-1) removed.			
74HC_HCT32 v.5	20120904	Product data sheet	-	74HC_HCT32 v.4
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>			
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>			propriate.
74HC_HCT32 v.4	20031212	Product specification	-	74HC_HCT32 v.3
74HC_HCT32 v.3	20030829	Product specification	-	74HC_HCT32_CNV v.2
74HC_HCT32_CNV v.2	19970827	Product specification	-	-

# 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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74HC HCT32

#### **Quad 2-input OR gate**

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